

SN74LVC828A 10-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS SCAS347H-MARCH 1994-REVISED MARCH 2005

FEATURES	DB, DGV, DW, NS, OR PW PACKAGE
Operates From 1.65 V to 3.6 V	(TOP VIEW)
Inputs Accept Voltages to 5.5 V	┛────┣…
 Max t_{pd} of 6.7 ns at 3.3 V 	OE1 1 24 V _{CC} A1 2 23 Y1
 Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, T_A = 25°C 	AT U 2 23 11 A2 [3 22] Y2 A3 [4 21] Y3
 Typical V_{OHV} (Output V_{OH} Undershoot) >2 V at V_{CC} = 3.3 V, T_A = 25°C 	A4 [5 20] Y4 A5 [6 19] Y5
 Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC}) 	A6 [7 18] Y6 A7 [8 17] Y7 A8 [9 16] Y8
 I_{off} Supports Partial-Power-Down Mode Operation 	A9 0 10 15 Y9 A10 11 14 Y10
 Latch-Up Performance Exceeds 250 mA Per JESD 17 	GND [12 13] OE2

- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

This 10-bit buffer/bus driver is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74LVC828A provides a high-performance bus interface for wide data paths or buses carrying parity.

The 3-state control gate is a 2-input AND gate with active-low inputs so that, if either output-enable (OE1 or OE2) input is high, all ten outputs are in the high-impedance state. The SN74LVC828A provides inverting data at its outputs.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

T _A	T _A PACH		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
		Tube of 25	SN74LVC828ADW	1.1/00004	
	SOIC – DW	Reel of 2000	SN74LVC828ADWR	LVC828A	
	SOP – NS	Reel of 2000	SN74LVC828ANSR	LVC828A	
4000 to 0500	SSOP – DB	Reel of 2000	SN74LVC828ADBR	LC828A	
–40°C to 85°C		Tube of 60	SN74LVC828APW		
	TSSOP – PW	Reel of 2000	SN74LVC828APWR	LC828A	
		Reel of 250	SN74LVC828APWT	-	
	TVSOP – DGV	Reel of 2000	SN74LVC828ADGVR	LC828A	

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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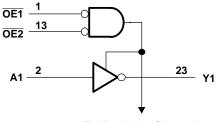
SN74LVC828A 10-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCAS347H-MARCH 1994-REVISED MARCH 2005

FUNCTION TABLE

Ī		INPUTS		OUTPUT
	OE1	OE2	Α	Y
Ī	L	L	L	Н
	L	L	Н	L
	н	Х	Х	Z
	Х	Н	Х	Z

LOGIC DIAGRAM (POSITIVE LOGIC)



To Nine Other Channels

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Voltage range applied to any output in the h	high-impedance or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage range applied to any output in the h	high or low state ⁽²⁾⁽³⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V ₀ < 0		-50	mA
I _O	Continuous output current		±50	mA	
	Continuous current through V_{CC} or GND			±100	mA
		DB package		63	
		DGV package		86	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DW package		46	°C/W
		NS package		65	
		PW package		88	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT	
V	Cupply voltage	Operating	1.65	3.6	V	
V _{CC}	Supply voltage	Data retention only	1.5		v	
		V _{CC} = 1.65 V to 1.95 V	$0.65 imes V_{CC}$			
VIH	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
VIL	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		
VI	Input voltage		0	5.5	V	
V	Output voltage	High or low state	0	V _{CC}	V	
Vo	Output voltage	3-state	0	5.5	v	
		V _{CC} = 1.65 V		-4		
	High lovel output ourrent	$V_{CC} = 2.3 V$		-8	mA	
I _{OH}	High-level output current	$V_{CC} = 2.7 V$		-12	ША	
		$V_{CC} = 3 V$		-24		
		V _{CC} = 1.65 V		4		
	Low level output ourrept	$V_{CC} = 2.3 V$		8	س ۸	
I _{OL}	Low-level output current	$V_{CC} = 2.7 V$		12	mA	
		$V_{CC} = 3 V$		24		
$\Delta t / \Delta v$	Input transition rise or fall rate			10	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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TEXAS INSTRUMENTS www.ti.com

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST C	ONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾	MAX	UNIT
	I _{OH} = −100 μA		1.65 V to 3.6 V	$V_{CC} - 0.2$			
	I _{OH} = -4 mA		1.65 V	1.2			
	I _{OH} = -8 mA		2.3 V	1.7			V
V _{OH}	L _ 12 mA		2.7 V	2.2			V
	I _{OH} = -12 mA		3 V	2.4			
	I _{OH} = -24 mA		3 V	2.2			
	I _{OL} = 100 μA		1.65 V to 3.6 V			0.2	
	$I_{OL} = 4 \text{ mA}$		1.65 V			0.45	
V _{OL}	I _{OL} = 8 mA		2.3 V			0.7	V
	I _{OL} = 12 mA		2.7 V			0.4	
	I _{OL} = 24 mA		3 V			0.55	
I _I	V _I = 0 to 5.5 V		3.6 V			±5	μA
l _{off}	$V_{I} \text{ or } V_{O} = 5.5 \text{ V}$		0			±10	μA
I _{OZ}	$V_0 = 0$ to 5.5 V		3.6 V			±10	μA
	$V_I = V_{CC}$ or GND		2.6.1/			10	۸
I _{CC}	$3.6 \text{ V} \le \text{V}_{\text{I}} \le 5.5 \text{ V}^{(2)}$	$I_{O} = 0$	3.6 V			10	μA
ΔI_{CC}	One input at V _{CC} – 0.6 V,	Other inputs at V_{CC} or GND	2.7 V to 3.6 V			500	μA
Ci	$V_I = V_{CC}$ or GND		3.3 V		5		pF
Co	$V_{O} = V_{CC}$ or GND		3.3 V		7		pF

All typical values are at V_{CC} = 3.3 V, T_A = 25^{\circ}C. This applies in the disabled state only. (1)

(2)

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	TER FROM (INPUT) (OU		V _{CC} = ± 0.1		V _{CC} = 1 ± 0.2		V _{CC} =	2.7 V	V _{CC} = 1 ± 0.3	3.3 V 3 V	UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	А	Y	(1)	(1)	(1)	(1)		7.1	1	6.7	ns
t _{en}	OE	Y	(1)	(1)	(1)	(1)		8.5	1	7.3	ns
t _{dis}	OE	Y	(1)	(1)	(1)	(1)		7.3	1.8	6.7	ns
t _{sk(o)}										1	ns

(1) This information was not available at the time of publication.

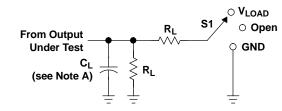
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER		TEST	V _{CC} = 1.8 V	V_{CC} = 2.5 V	V_{CC} = 3.3 V	UNIT
		CONDITIONS	TYP	TYP	TYP	UNIT	
6	Power dissipation capacitance	Outputs enabled	£ 10 MU	(1)	(1)	24	ρF
C _{pd}	per buffer/driver	Outputs disabled	f = 10 MHz	(1)	(1)	7	рг

(1) This information was not available at the time of publication.

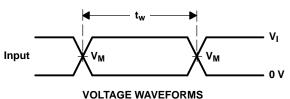
PARAMETER MEASUREMENT INFORMATION



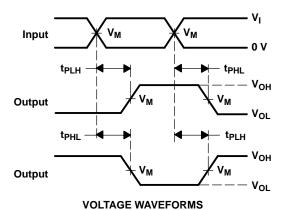
LOAD CIRCUIT

TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

	INF	PUTS		N.	•	-	
V _{CC}	VI	t _r /t _f	VM	V _{LOAD}	C∟	RL	V_{Δ}
$\textbf{1.8 V} \pm \textbf{0.15 V}$	v _{cc}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
$\textbf{2.5 V} \pm \textbf{0.2 V}$	Vcc	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V

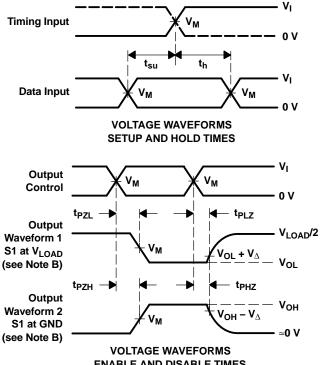


PULSE DURATION



PROPAGATION DELAY TIMES

INVERTING AND NONINVERTING OUTPUTS



ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_{L} includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



5-Aug-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LVC828ADBLE	OBSOLETE	SSOP	DB	24		TBD	Call TI	Call TI	-40 to 85		
SN74LVC828ADBR	OBSOLETE	SSOP	DB	24		TBD	Call TI	Call TI	-40 to 85		
SN74LVC828ADBRE4	OBSOLETE	SSOP	DB	24		TBD	Call TI	Call TI	-40 to 85		
SN74LVC828ADBRG4	OBSOLETE	SSOP	DB	24		TBD	Call TI	Call TI	-40 to 85		
SN74LVC828ADGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LC828A	Samples
SN74LVC828ADW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC828A	Samples
SN74LVC828ADWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC828A	Samples
SN74LVC828APW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LC828A	Samples
SN74LVC828APWLE	OBSOLETE	TSSOP	PW	24		TBD	Call TI	Call TI	-40 to 85		
SN74LVC828APWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LC828A	Samples
SN74LVC828APWT	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LC828A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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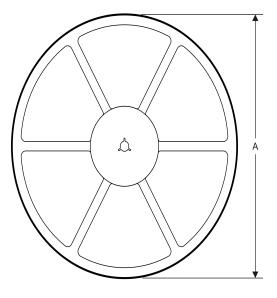
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

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TAPE AND REEL INFORMATION

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC828ADGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC828ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVC828APWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74LVC828APWT	TSSOP	PW	24	250	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

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PACKAGE MATERIALS INFORMATION

17-Aug-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC828ADGVR	TVSOP	DGV	24	2000	367.0	367.0	35.0
SN74LVC828ADWR	SOIC	DW	24	2000	367.0	367.0	45.0
SN74LVC828APWR	TSSOP	PW	24	2000	367.0	367.0	38.0
SN74LVC828APWT	TSSOP	PW	24	250	367.0	367.0	38.0

MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



LAND PATTERN DATA



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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